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Features and Benefits

6A Continuous Current

Low R_{DS(ON)} Internal NFETs

35µA Low Quiescent Current

200µs Turn On Rise Time

3.2V to 5.5V Bias Voltage

DML1007LDS

SINGLE CHANNEL SMART LOAD SWITCH

Description and Applications

The DML1007LDS is a single channel load switch with very low onresistance in a small package. It contains an N-channel MOSFET for up to V_{BIAS}-1.5V input voltage operation and 6A current channel with 3.2V to 5.5V bias supply. The load switch is controlled by a low voltage control signal through ON pin.

- Portable Computers
- Ultrabooks
- Tablet PCs
- Set Top Boxed
- LCD TV
- Telecom/Networking/Datacom Equipment
- SSD
- Consumer Electronics

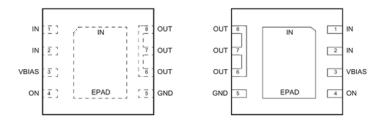
V-DFN3030-8 (Type R)





Top View

Bottom View



Low R_{DS(ON)} – Ensures On State Losses Are Minimized

Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3)

0.8V to VBIAS-1.5V Input Voltage Range

 $8m\Omega$ at $V_{BIAS} = 5V$, $V_{IN} = 1.05V$, $T_A = +85^{\circ}C$

Integrated Quick Output Discharge Resistor

Ordering Information (Note 4)

Part Number	Case	Packaging
DML1007LDS-7	V-DFN3030-8 (Type R)	3000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

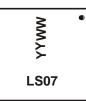
4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Pin Description

Pin Number	Pin Name	Pin Function
1. 2. EPAD	IN	Load Switch Input. Bypass capacitor is recommended to minimize input voltage dip. Recommended
1, 2, EFAD	IIN	voltage range of this pin is 0.8V to V_{BIAS} -1.5V to obtain optimal R_{ON} .
3	VBIAS	Bias Voltage. Power supply input for the device. Recommended voltage range is 3.2V to 5.5V.
4	ON	Enable Input. Load switch is on when ON is pulled high. Load switch is off when ON is pulled low.
4		Do not leave floating.
5	GND	Ground.
6, 7, 8	OUT	Load switch output.

Marking Information

V-DFN3030-8 (Type R)

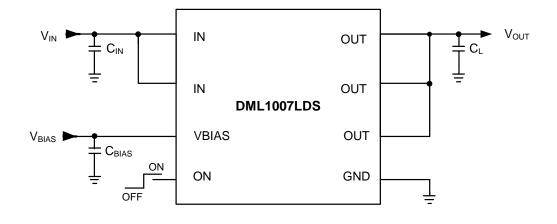


LS07= Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 16 = 2016) WW = Week Code (01 to 53)

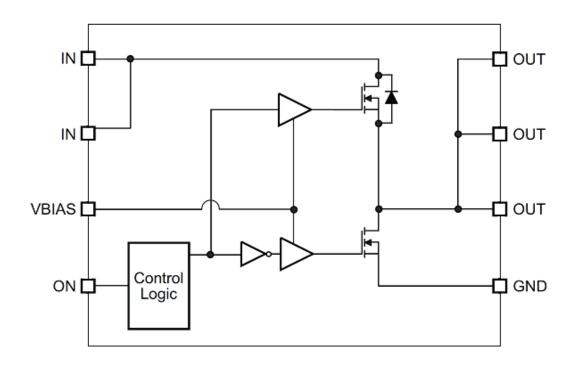
^{2.} See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.



Typical Application



Functional Block Diagram





Absolute Maximum Ratings

Parameter	Rating
IN, ON, VBIAS, OUT to GND	-0.3V to 6V
Junction Temperature (T _J)	+150°C
Storage Temperature (T _S)	-65°C to +150°C
ESD Rating HBM/CDM	2kV/1kV

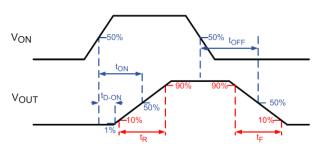
Maximum Operating Ratings

Parameter	Rating		
Supply Voltage (V _{IN})	V _{BIAS} -1.5V		
Ambient Temperature (T _A)	-40°C to +85°C		
Package Thermal Resistance (θ_{JC})	8°C/W		
Package Thermal Resistance (θ _{JA})	60°C/W		

Electrical Characteristics (T_A = +25°C, V_{BIAS} = 5V, V_{IN} = 1.05V, unless otherwise specified.)

Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
VIN	IN Supply Voltage	$V_{ON} = 5V$	0.8	1.05	V _{BIAS} -1.5	V
VBIAS	VBIAS Supply Voltage	—	3.2	5	5.5	V
ID	Maximum Continuous Current	$V_{ON} = 5V$	—	6	—	Α
IPLS	Maximum Pulsed Switch Current	V _{IN} = V _{ON} = 5V Pulse < 300µs, 2% Duty Cycle	_	12	_	А
lq	Quiescent Supply Current of VBIAS	$I_{OUT} = 0V, V_{ON} = 5V$	—	35	—	μA
IOFF	VBIAS Shutdown Supply Current	$V_{ON} = 0V, V_{OUT} = 0V$	—	—	2	μA
IINOFF	IN Shutdown Supply Current	$V_{ON} = 0V, V_{OUT} = 0V$	—	—	2	μA
I _{ON}	ON Leakage Current	$V_{ON} = 5V$	—	—	1	μA
Vonh	ON High Level Voltage	—	1.2	_	_	V
Vonl	ON Low Level Voltage	—	_	—	0.5	V
Switching	ON Resistance	·		•		
		I_{OUT} = -200mA, V_{ON} = 5V, V_{BIAS} = 5V	—	—	8	mΩ
R _{ON}	Switch ON-State Resistance	I_{OUT} = -200mA, V_{ON} = 5V, V_{BIAS} = 3.3V	—	_	10	mΩ
R _{PD}	Output Pull-Down Resistance	$I_{OUT} = 15 \text{mA}, V_{ON} = 0 \text{V}$	_	_	200	Ω

Switching Characteristics

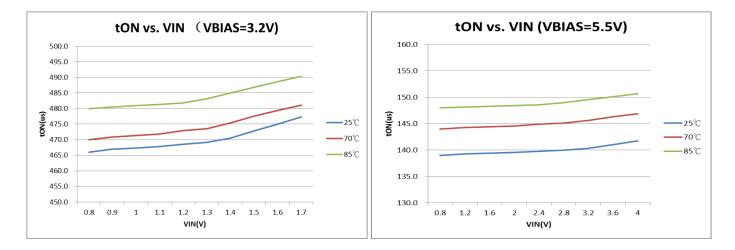


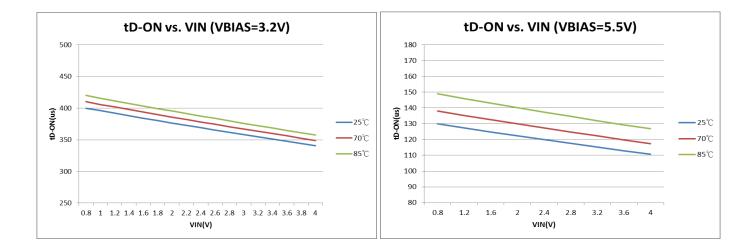
Test conditions: $T_A = +25^{\circ}C$, $C_{IN} = 1\mu$ F, $C_L = 0.1\mu$ F, $R_L = 10\Omega$ (unless otherwise specified).

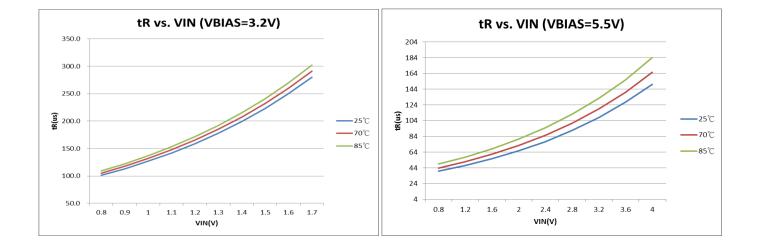
Symbol	Parameter	Min	Тур	Max	Unit
V _{IN} = 1.5V,	V _{BIAS} = V _{ON} = 5V				
t _{ON}	Turn-ON Time		200	—	
t _{D-ON}	Turn-ON Delay Time		100	—	
t _R	Turn-ON Rise Time		150	—	μs
tOFF	Turn-OFF Time	_	1	—	
tF	Turn-OFF Fall Time	_	1	—	
V _{IN} = 1.05V	$V_{BIAS} = V_{ON} = 5V$				
ton	Turn-ON Time		200	—	
t _{D-ON}	Turn-ON Delay Time		100	—	
t _R	Turn-ON Rise Time	_	150	—	μs
tOFF	Turn-OFF Time	_	0.7	—	
t _F	Turn-OFF Fall Time		0.7	—	



Typical Characteristics

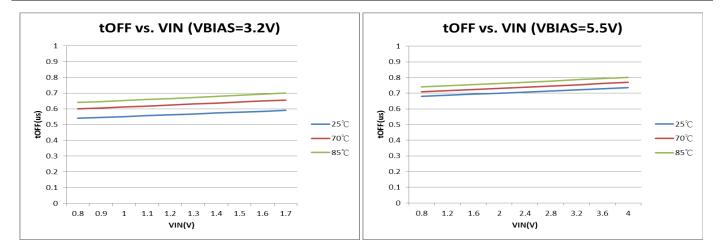


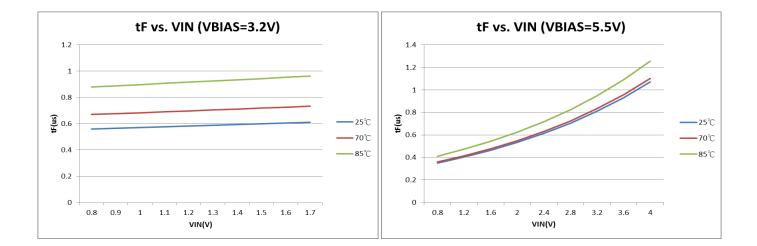






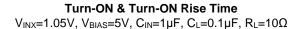
Typical Characteristics (Cont.)

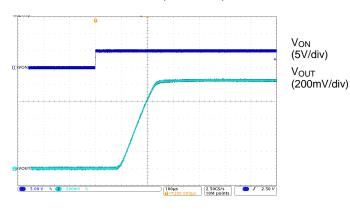




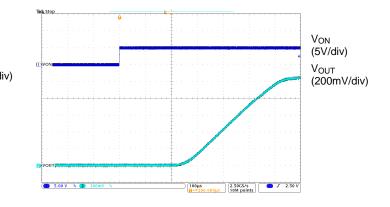


Functional Characteristics

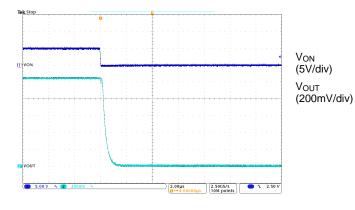




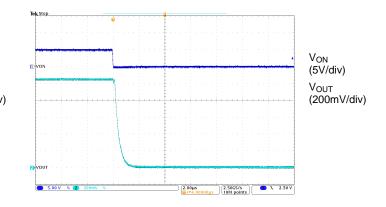
 $\label{eq:transformation} \begin{array}{c} \textbf{Turn-ON \& Turn-ON Rise Time} \\ V_{\text{INX}} = 1.05 V, \ V_{\text{BIAS}} = 3.2 V, \ C_{\text{IN}} = 1 \mu F, \ C_{\text{L}} = 0.1 \mu F, \ R_{\text{L}} = 10 \Omega \end{array}$



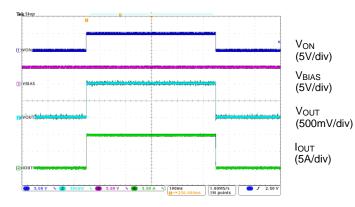
 $\label{eq:VINX} \begin{array}{l} \mbox{Turn-OFF \& Turn-OFF FALL Time} \\ V_{INX} = 1.05V, \ V_{BIAS} = 5V, \ C_{IN} = 1\mu F, \ C_L = 0.1\mu F, \ R_L = 10\Omega \end{array}$



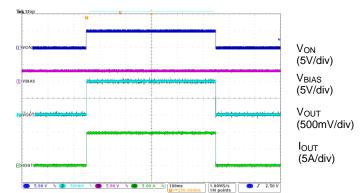
 $\label{eq:transform} \begin{array}{l} \mbox{Turn-OFF & Turn-OFF FALL Time} \\ V_{\text{INX}}{=}1.05V, \ V_{\text{BIAS}}{=}3.2V, \ C_{\text{IN}}{=}1\mu\text{F}, \ C_{\text{L}}{=}0.1\mu\text{F}, \ R_{\text{L}}{=}10\Omega \end{array}$



Turn-ON & Turn-OFF at I_{OUT} = -10A V_{INX} =1.05V, V_{BIAS} =5V, C_{IN} =1 μ F, C_L =0.1 μ F, R_L =0.1 Ω



Turn-ON & Turn-OFF at I_{OUT}= -10A V_{INX} =1.05V, V_{BIAS} =3.2V, C_{IN} =1 μ F, C_{L} =0.1 μ F, R_{L} =0.1 Ω





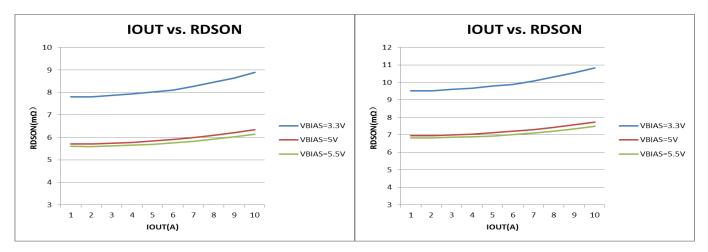
Detailed Description

ON/OFF Control

The DML1007LDS is enabled when the ON pin is on active high with 1.2V or above voltage. The device is disabled when the ON pin voltage is 0.5V or lower. The EN input is compatible with both TTL and CMOS logic.

VBIAS Voltage Range

For optimal on-resistance of load switch, make sure $V_{IN} \le 1.5V + V_{BIAS}$ and V_{BIAS} is within the voltage range from 3.2V to 5.5V. On-resistance of load switch will be higher if $V_{IN} + 1.5V > V_{BIAS}$. Resistance curves of a typical sample device at different $V_{BIAS} = V_{IN}$ at $I_{OUT} = -200$ mA are shown as below.



Applications Information

The basic DML1007LDS application circuit is shown in the second page. Component selection is explained below.

Input Capacitor

A capacitor of 10µF or higher value is recommended to be placed close to the IN pins of DML1007LDS. This capacitor can reduce the voltage drop caused by the in-rush current during the turn-on transient of the load switch. A higher value capacitor can be used to further reduce the voltage drop during high-current application.

Output Capacitor

A capacitor of 0.1µF or higher value is recommended to be placed between the OUT pins and GND. The switching times are affected by the capacitance. A larger capacitor makes the initial turn-on transient smoother. This capacitor must be large enough to supply a fast transient load in order to prevent the output from dropping.

Thermal Considerations

To ensure proper operation, the maximum junction temperature of the DML1007LDS should not exceed +150°C. Several factors attribute to the junction temperate rise: load current, MOSFET on-resistance, junction-to-ambient thermal resistance, and ambient temperature. The maximum load current can be determined by:

$$I_{LOAD(MAX)} = \sqrt{\frac{T_{J(MAX)} - T_{C}}{\Theta_{JC} \times R_{DS(ON)}}}$$

It is noted that the maximum continuous load current is 6A.

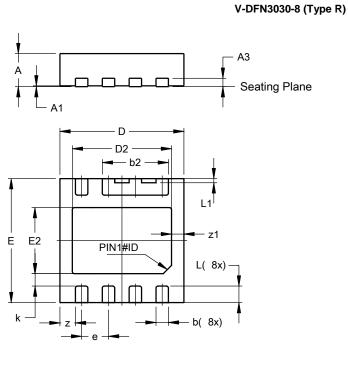
Layout Guidelines

Good PCB is important for improving the thermal performance of DML1007LDS. Place the input and output bypass capacitors close to the IN and OUT pins. The input and output PCB traces should be as wide as possible for the given PCB space. Use a ground plane to enhance the power dissipation capability of the device.



Package Outline Dimensions

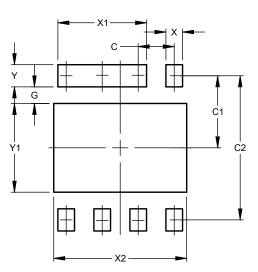
Please see http://www.diodes.com/package-outlines.html for the latest version.



	V-DFN3030-8								
(Type R)									
Dim	Dim Min Max Typ								
Α	0.77	0.83	0.80						
A1	0.00	0.05	0.03						
A3			0.203						
b	0.25	0.35	0.30						
b2	1.55	1.65	1.60						
D	2.95	3.05	3.00						
D2	2.30	2.50	2.40						
Е	2.95	3.05	3.00						
E2	1.50	1.70	1.60						
e		0.65 B	SC						
k	1		0.30						
L	0.35	0.45	0.40						
L1	0.05	0.15	0.10						
z			0.375						
z1			0.30						
All	Dimen	sions i	All Dimensions in mm						

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

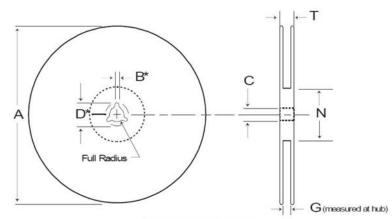


Dimensions	Value (in mm)
С	0.65
C1	1.30
C2	2.60
G	0.30
Х	0.30
X1	1.60
X2	2.40
Ý	0.40
Y1	1.60

V-DFN3030-8 (Type R)

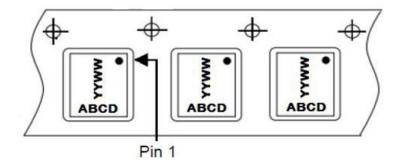


Surface Mount Reel Specifications (All dimensions in mm.)

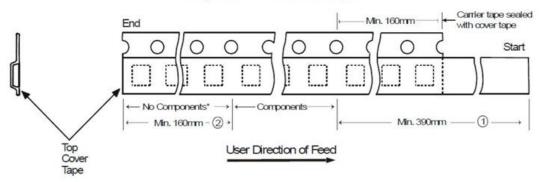


* Drive spokes optional. If used, dimensions with asterisks apply.

Tape Size	A Max	B* Max	с	D* Max	N Min	G	T Max
	330 ±2	2.0 +0.5 -0	13 +0.5 -0.2	20.5 _{±0.2}	100 ±2	8.4 _{+2.0} -0.0	14.4
8mm -	178 ±2	2.0 +0.5 -0	13 +0.5 -0.2	20.5 ±0.2	55 _{±5}	81.45	14.4



Tape Leader and Trailer



Notes: 5. There shall be a leader of 230mm [9.05 inches] minimum which may consist of carrier and/or cover tape or a start tape followed by a minimum of

There shall be a trailer of 160mm [6.30 inches] minimum winder tape.
There shall be a trailer of 160mm [6.30 inches] minimum of empty carrier tape sealed with cover tape.
There shall be a trailer of 160mm [6.30 inches] minimum of empty carrier tape sealed with cover tape.



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